

General J-FET input dual operational amplifier

summary

The TL082 is a high-speed dual operational amplifier with high-speed J-FET input, consisting of a high-voltage J-FET and a bipolar transistor. It has a high switching rate, low input bias current and offset current, and a very low offset voltage temperature coefficient. The operating range is 0 --70 .

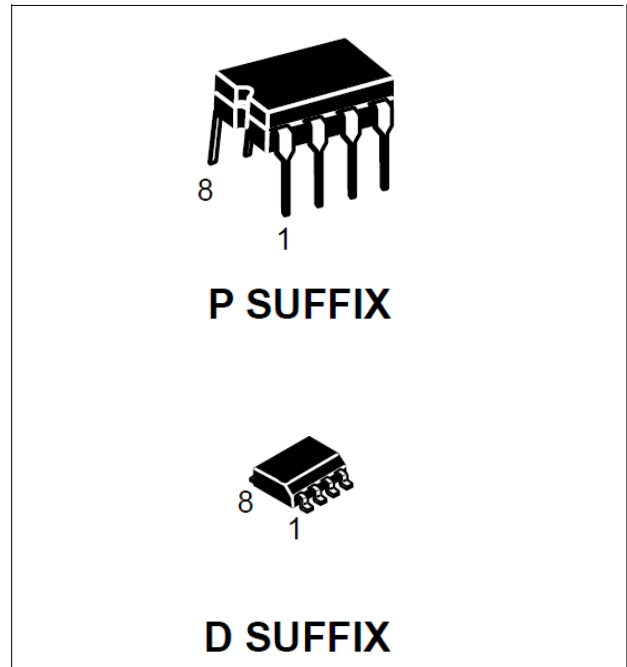
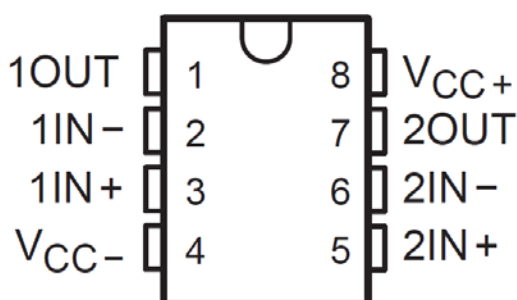
TL082 Provides DIP8 and SOP8 packages.

main features

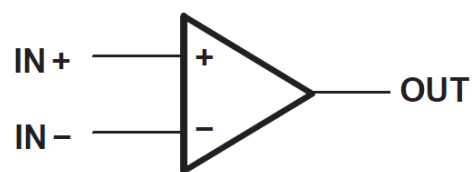
- Lower power consumption
- Wide common and differential mode input voltage range
- Low input bias current and offset current
- Output short circuit current protection
- high input impedance
- High conversion rate
- High gain bandwidth product, up to 4MHz pin

diagram

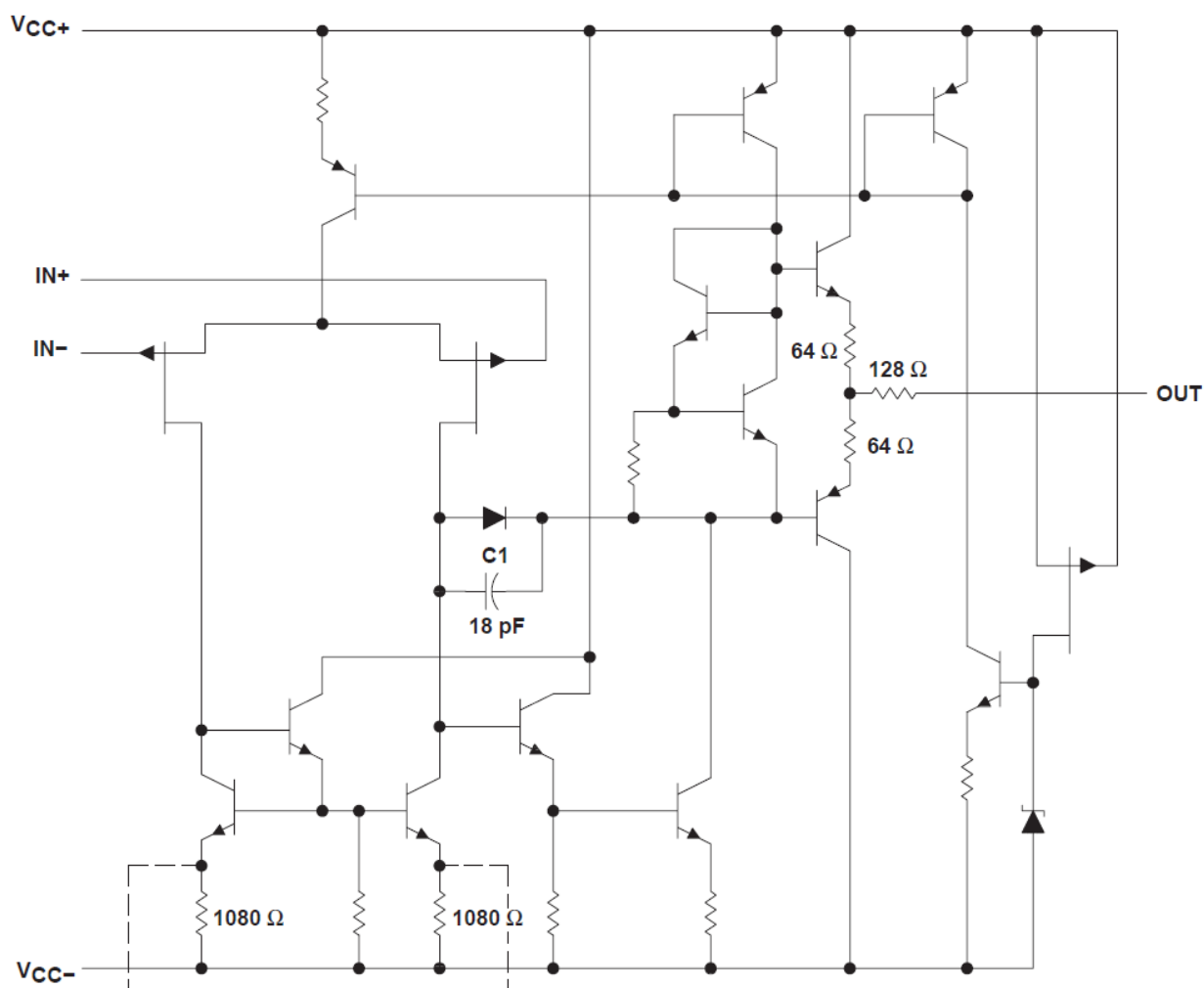
(TOP VIEW)



Symbols (per amplifier)



Internal block diagram (each amplifier)



absolute rating

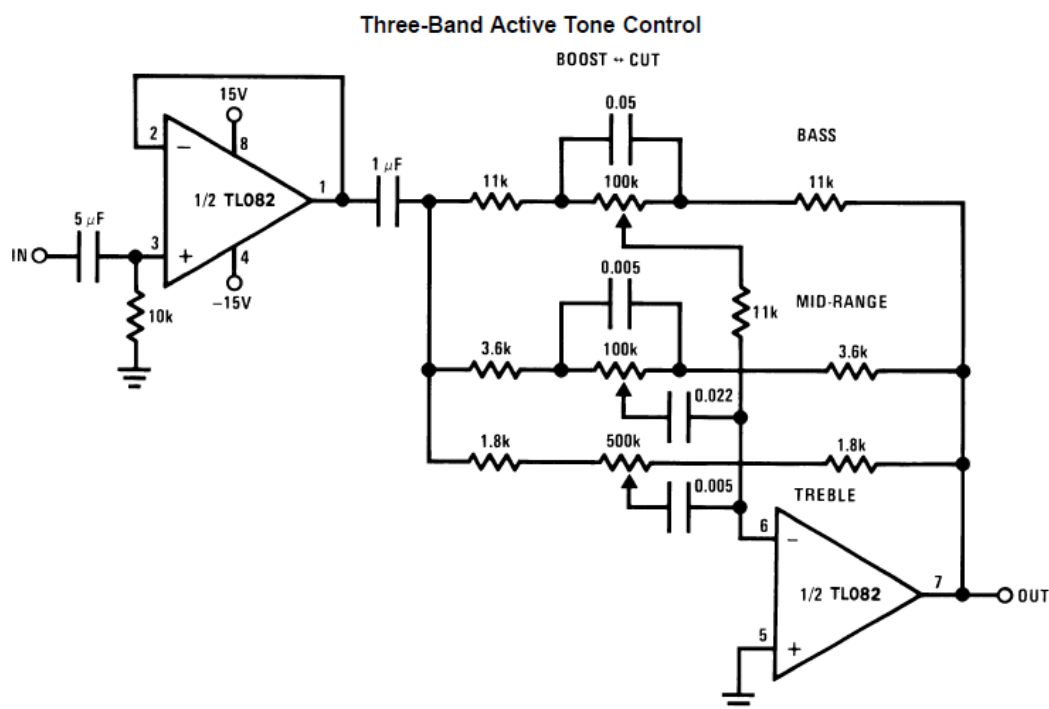
Symbol	Description	Extreme	Unit
Vcc	Supply voltage	± 18	V
Vi	Input voltage	± 14	V
Vid	Differential mode input voltage	± 28	V
Toper	Working temperature	0—70	°C
Tstg	Storage temperature	-65—150	°C

Electrical characteristics ($V_{CC}=\pm 15$, $T_{amp}=25$ special conditions are explained separately)

Symbol	Parameter name	Test condition	Test value			Unit
			Min	Typ	Max	
V_{io}	Offset voltage	$V_o=0V$		3	6	mV
I_{io}	Input offset current	$V_o=0V$			1.5	nA
I_{ib}	Output bias current	$V_o=0V$			2.5	nA
V_{icr}	Enter the common mode voltage		-12	± 11	15	V
V_{om}	Output voltage peak	$R_L = 10\text{ k}\Omega$ $R_L \geq 2\text{ k}\Omega$	± 12 ± 10	± 13.5 ± 12.5		V
AVD	Large signal voltage gain	$R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	80	95		dB
B1	Gain bandwidth product			3		MHz
CMRR	Cmrr		70	85		dB
kSVR	Power supply rejection ratio	$V_{CC} = \pm 15\text{ V}$ to $\pm 9\text{ V}$ $V_o=0V$	70	86		dB
ICC	Static current-per channel			1.4	2.8	mA
SR	Slew rate	$V_I = 10\text{ V}$,	8	13		V/ μ s
tr	Rise time			0.05		μ s

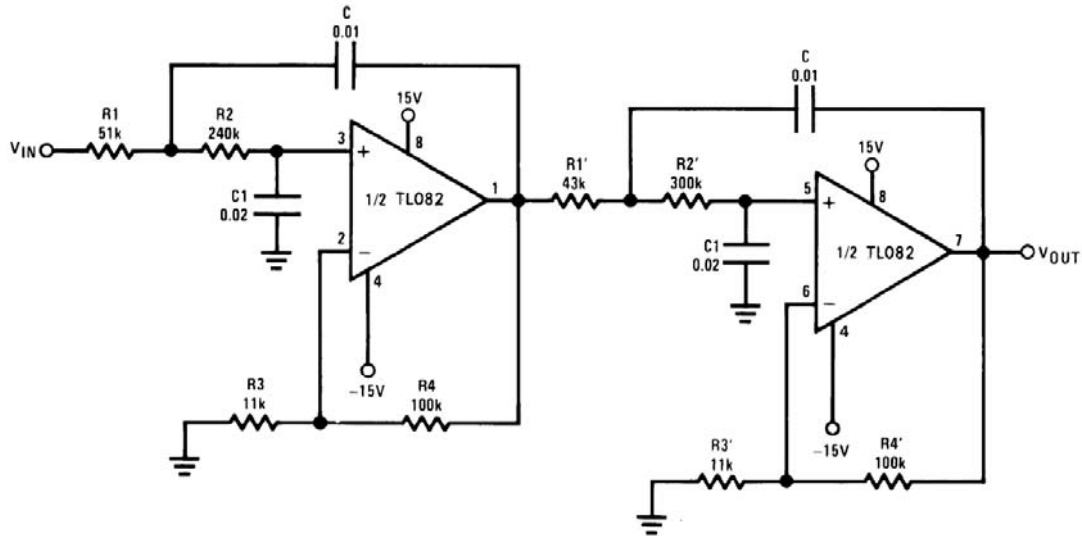
Application circuit diagram typical (one of the operational amplifiers)

1) Three tone control Three-Band Active Tone Control



2) Fourth order low pass filter

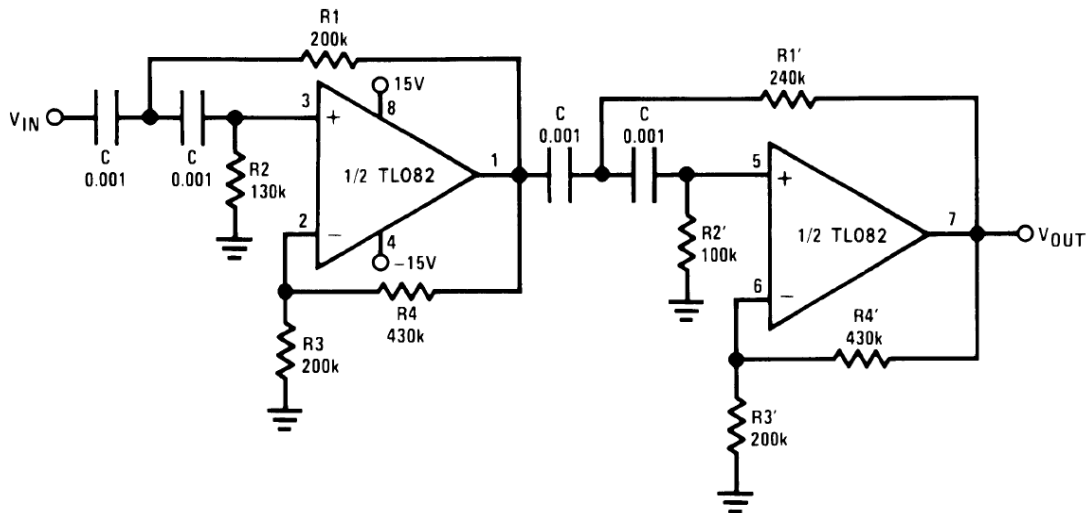
Fourth Order Low Pass Butterworth Filter



- Corner frequency (f_c) = $\sqrt{\frac{1}{R_1 R_2 C C_1}} \cdot \frac{1}{2\pi} = \sqrt{\frac{1}{R_1' R_2' C C_1}} \cdot \frac{1}{2\pi}$
- Passband gain (H_O) = $(1 + R_4/R_3) (1 + R_4'/R_3')$
- First stage $Q = 1.31$
- Second stage $Q = 0.541$
- Circuit shown uses nearest 5% tolerance resistor values for a filter with a corner frequency of 100 Hz and a passband gain of 100
- Offset nulling necessary for accurate DC performance

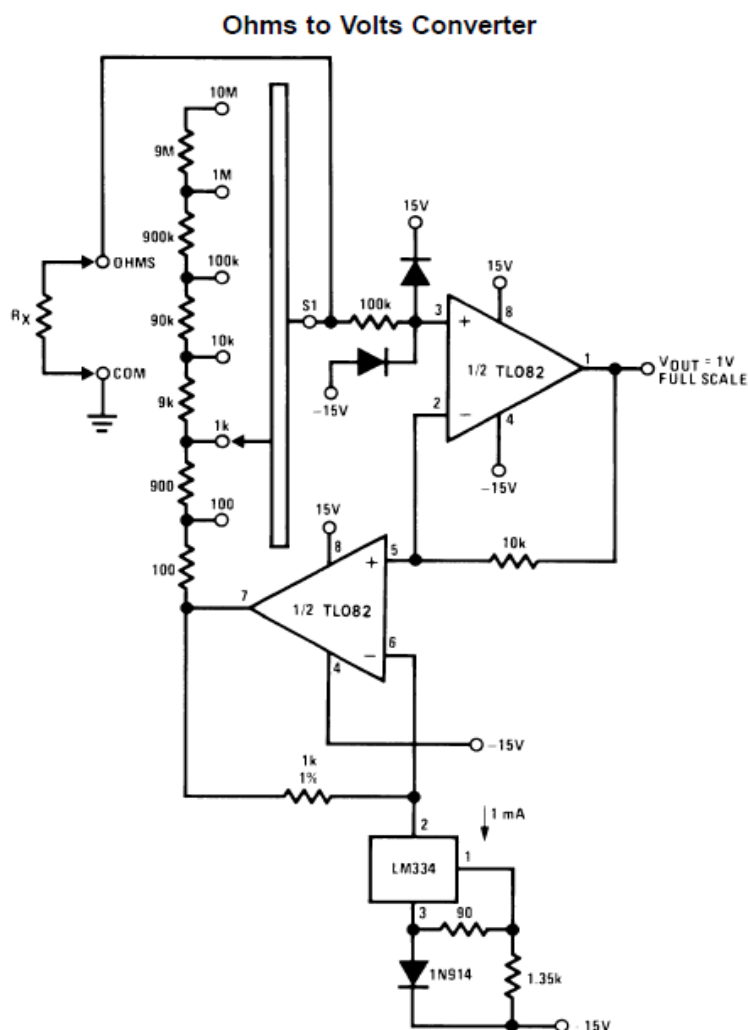
3) Fourth order high pass filter

Fourth Order High Pass Butterworth Filter



- Corner frequency (f_c) = $\sqrt{\frac{1}{R_1 R_2 C^2}} \cdot \frac{1}{2\pi} = \sqrt{\frac{1}{R_1' R_2' C^2}} \cdot \frac{1}{2\pi}$
- Passband gain (H_O) = $(1 + R_4/R_3) (1 + R_4'/R_3')$
- First stage $Q = 1.31$
- Second stage $Q = 0.541$
- Circuit shown uses closest 5% tolerance resistor values for a filter with a corner frequency of 1 kHz and a passband gain of 10

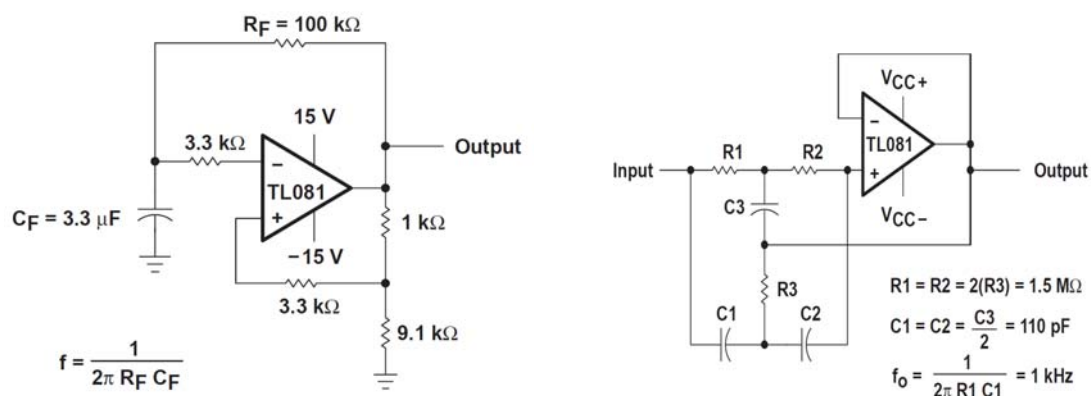
4) Conversion of resistance voltage



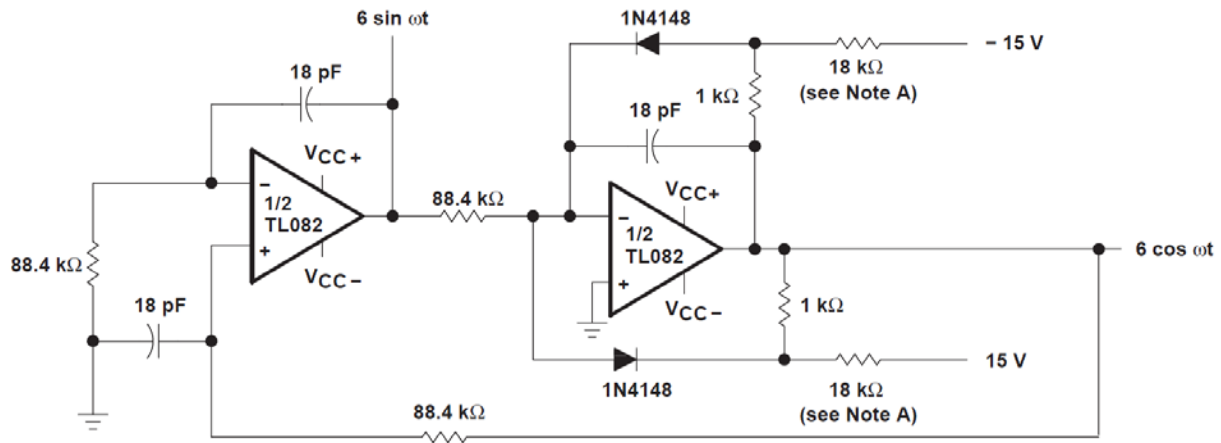
$$V_O = \frac{1V}{R_{LADDER}} \times R_X$$

Where R_{LADDER} is the resistance from switch S1 pole to pin 7 of the TL082CP.

5) Typical route

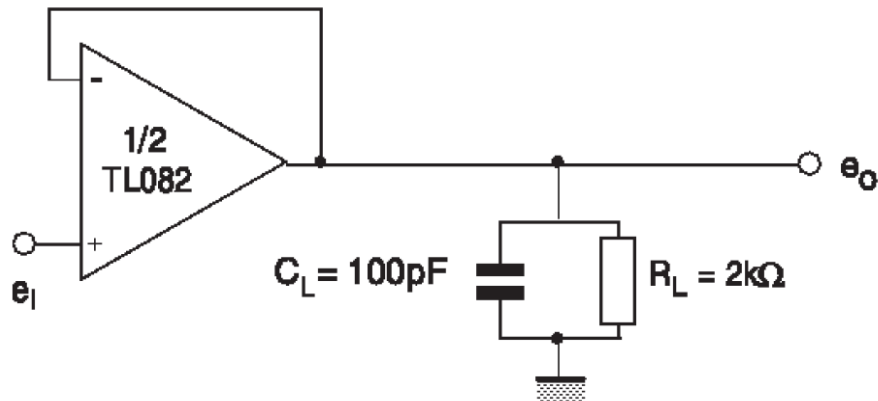


6) 100 kHz orthogonal oscillator 100-KHz Quadrature Oscillator

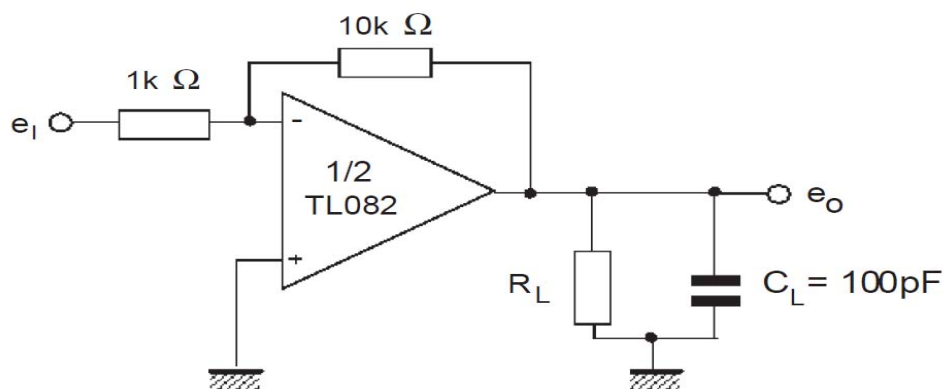


NOTE A: These resistor values may be adjusted for a symmetrical output.

7) Voltage follower Voltage Follower



8) The gain is 10 The inverting amplifier has a gain of 10 Inverting Amplifier



DIP8